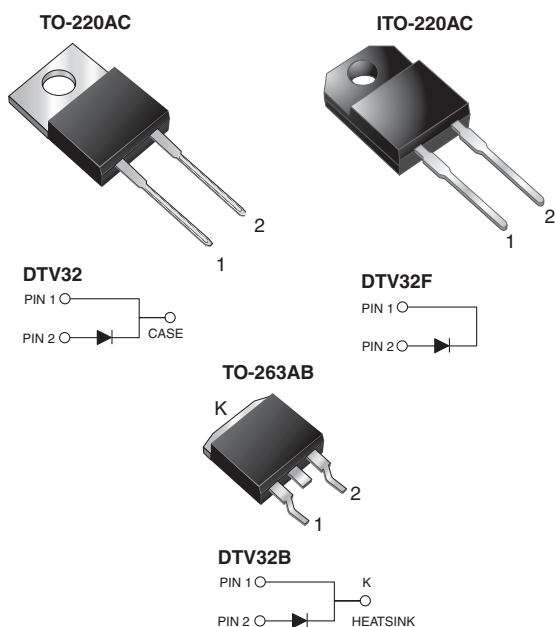




High Voltage Damper Diodes



FEATURES

- Glass passivated chip junction
- High breakdown voltage capability
- Very fast reverse recovery time
- Fast forward recovery time
- High efficiency, low switching losses
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AC and ITO-220AC package)
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high resolution display TV and monitor horizontal deflection application.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	10 A
V_{RRM}	1500 V
t_{rr}	175 ns
t_{fr}	280 ns
V_F	1.35 V

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, TO263AB

Epoxy meets UL 94 V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_C = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	1500	V
Maximum RMS voltage	V_{RMS}	1050	V
Maximum DC blocking voltage	V_{DC}	1500	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	10	A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	130	A
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150	°C
Isolation voltage (ITO-220AC only) from terminal to heatsink $t = 1\text{ min}$	V_{AC}	1500	V

DTV32, DTV32F, DTV32B

Vishay General Semiconductor

**ELECTRICAL CHARACTERISTICS** ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	$I_F = 6\text{ A}$ $I_F = 6\text{ A}$	$T_J = 25\text{ }^{\circ}\text{C}$ $T_J = 125\text{ }^{\circ}\text{C}$	V_F	1.5 1.35	V
Maximum DC reverse current at V_{RRM}		$T_J = 25\text{ }^{\circ}\text{C}$ $T_J = 125\text{ }^{\circ}\text{C}$	I_R	100 1.0	μA mA
Maximum reverse recovery time	$I_F = 1.0\text{ A}$, $di/dt = 50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $I_{rr} = 0.1 I_{RM}$		t_{rr}	175	ns
Typical forward recovery time	$I_F = 6\text{ A}$, $di/dt = 48\text{ A}/\mu\text{s}$, $V_{FR} = 3\text{ V}$		t_{fr}	280	ns
Peak forward recovery overshoot voltage	$I_F = 6\text{ A}$, $di/dt = 48\text{ A}/\mu\text{s}$, $T_J = 100\text{ }^{\circ}\text{C}$	typical maximum	V_{FP}	8 12	V

Note:(1) Pulse test: 300 μs pulse width, 2 % duty cycle**THERMAL CHARACTERISTICS** ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	DTV32	DTV32B	DTV32F	UNIT
Typical thermal resistance from junction to case	$R_{\theta JC}$	2.0		4.0	$^{\circ}\text{C}/\text{W}$

ORDERING INFORMATION (Example)

PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AC	DTV32-E3/45	1.80	45	50/tube	Tube
ITO-220AC	DTV32F-E3/45	1.95	45	50/tube	Tube
TO-263AB	DTV32B-E3/45	1.77	45	50/tube	Tube
TO-263AB	DTV32B-E3/81	1.77	81	800/reel	Tape and reel

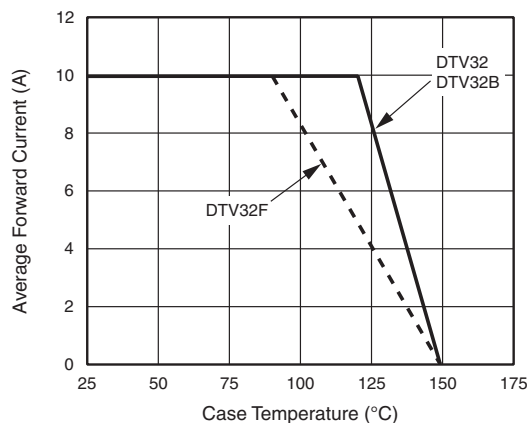
RATINGS AND CHARACTERISTICS CURVES($T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Figure 1. Forward Current Derating Curve

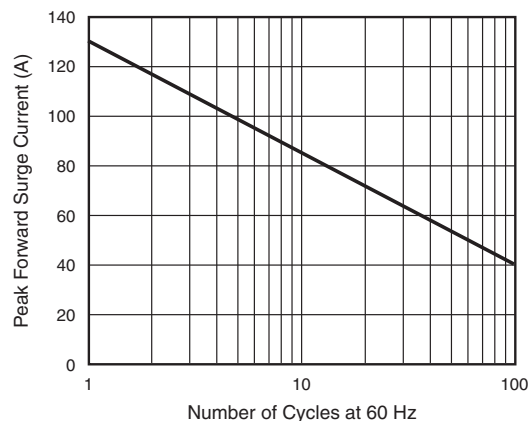


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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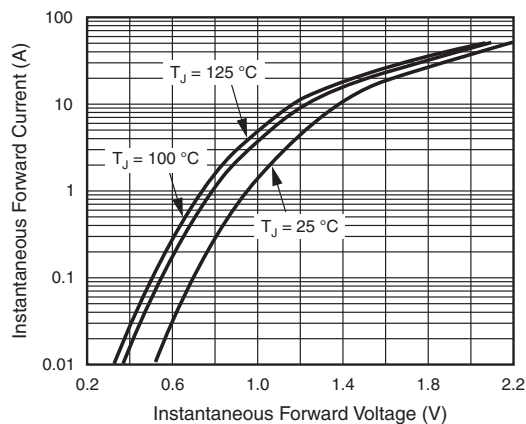


Figure 3. Typical Forward Voltage

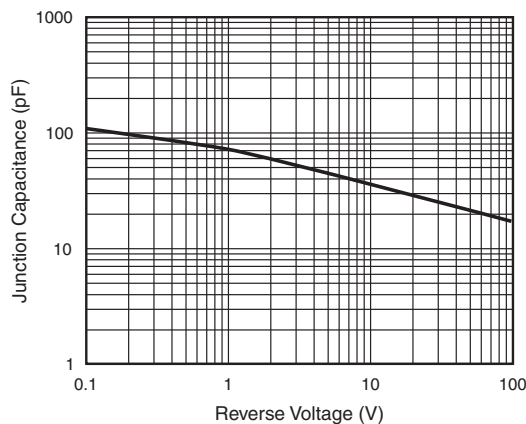


Figure 5. Typical Capacitance

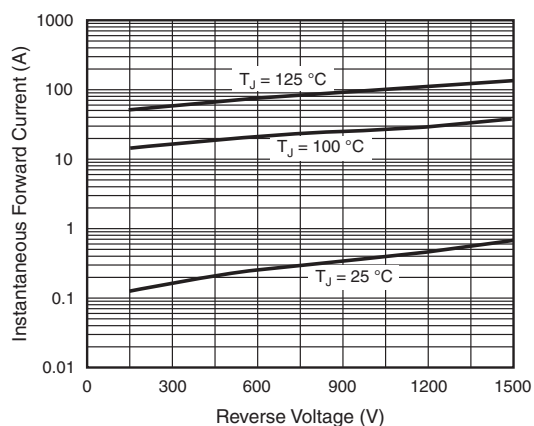


Figure 4. Typical Reverse Current

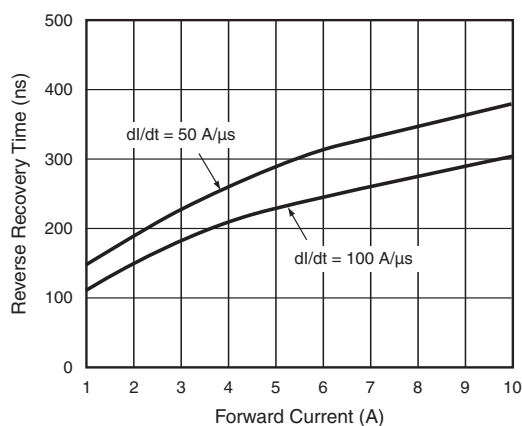


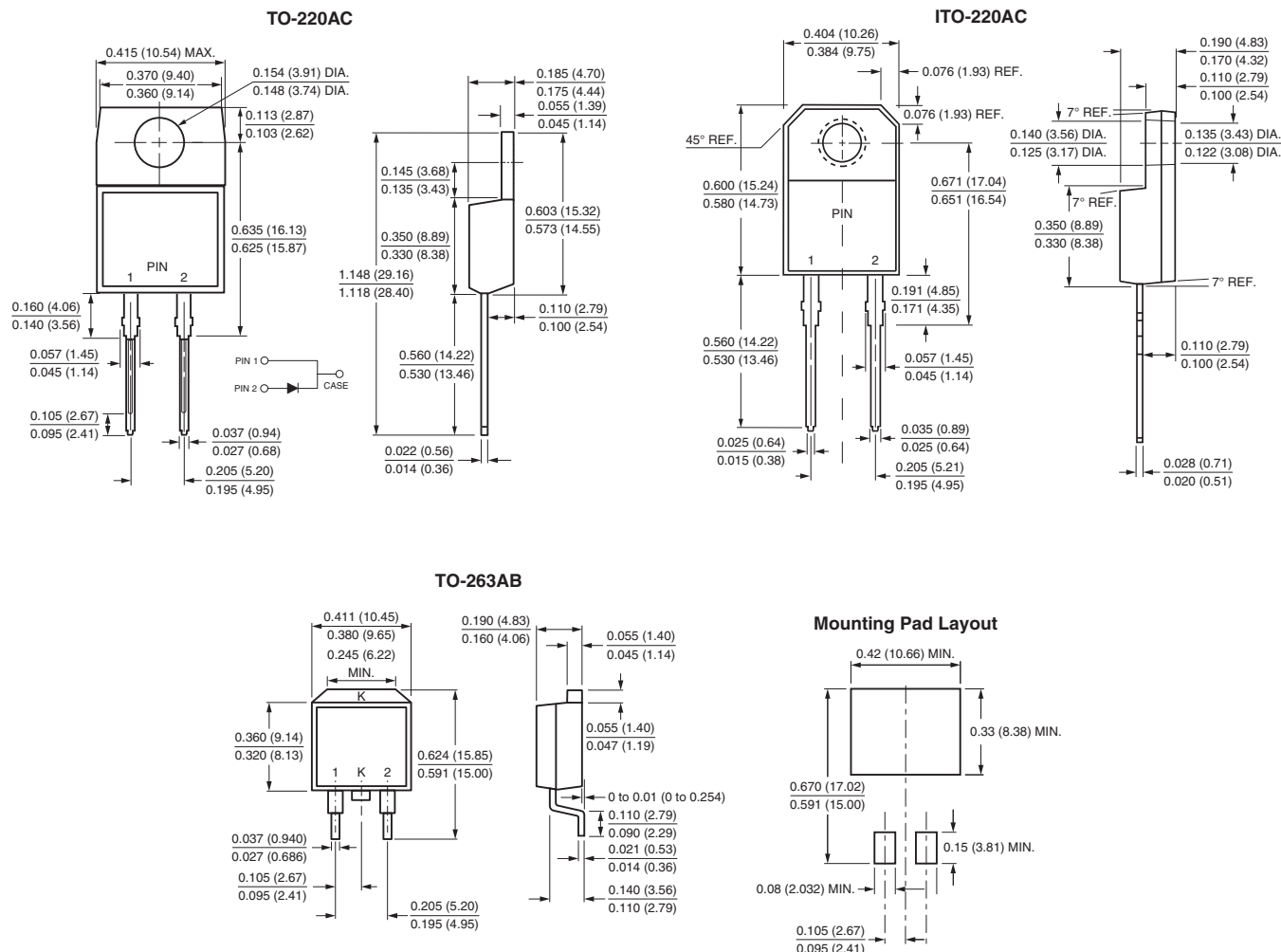
Figure 6. Typical Reverse Recovery Time

DTV32, DTV32F, DTV32B

Vishay General Semiconductor



PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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